

# 2MBI600XHA120-50

IGBT Modules

**Power Module (X series)**  
**1200V / 600A / 2-in-1 package**

■ **Features**

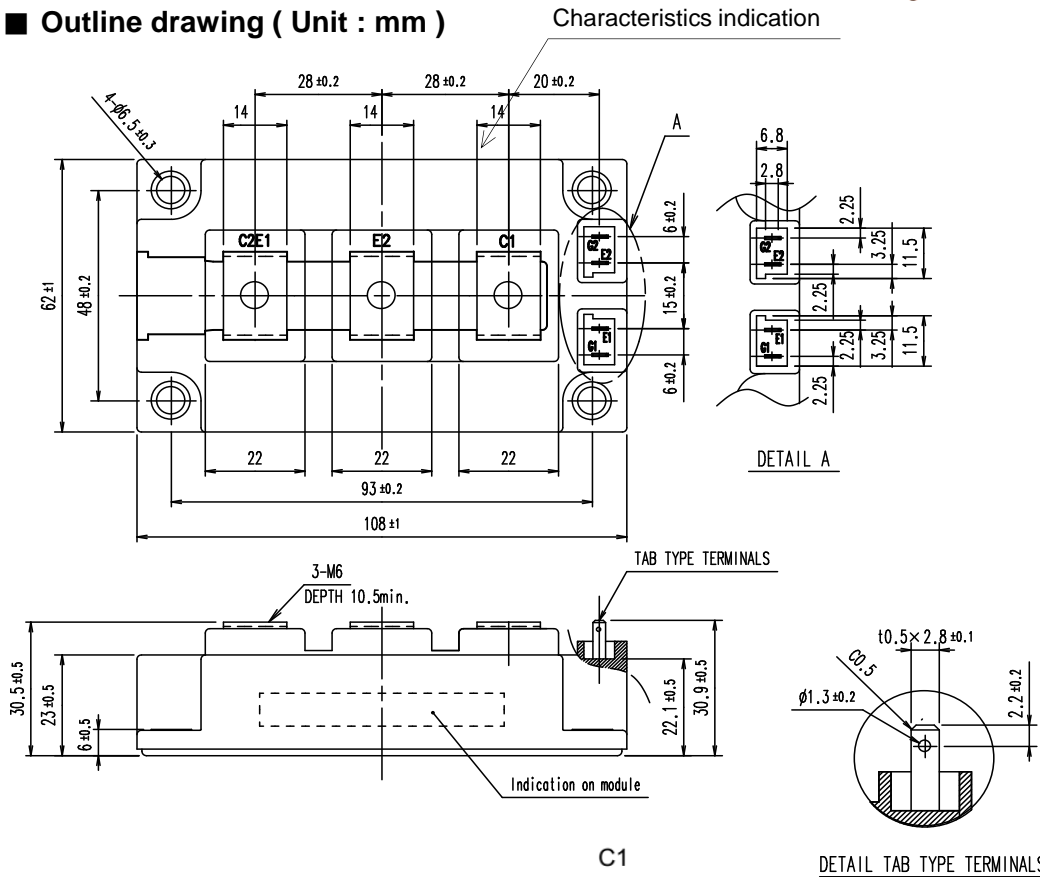
- LOW  $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines

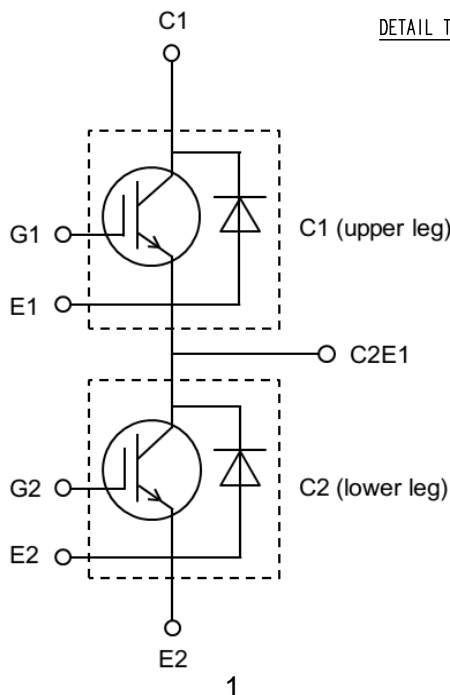


■ **Outline drawing ( Unit : mm )**



Weight: 370 g(typ.)

■ **Equivalent Circuit**



# 2MBI600XHA120-50

**IGBT Modules**
**■ Absolute Maximum Ratings (at  $T_C=25^\circ\text{C}$  unless otherwise specified)**

Items		Symbols	Conditions	Maximum Ratings	Units
Inverter	Collector-Emitter voltage Gate-Emitter short-circuited	$V_{CES}$		1200	V
	Gate-Emitter voltage Collector-Emitter short-circuited	$V_{GES}$		$\pm 20$	V
	Collector current	$I_C$	Continuous   $T_C=100^\circ\text{C}$	600	A
	Repetitive peak collector current	$I_{CRM}$	1ms	1200	
	Forward current	$I_F$		600	
	Repetitive peak forward current	$I_{FRM}$	1ms	1200	
	Total power dissipation	$P_{tot}$	1 device	2340	W
	Virtual junction temperature	$T_{vj}$		175	$^\circ\text{C}$
	Operating virtual junction temperature	$T_{vjop}$		175	
	Case temperature	$T_c$		125	
Storage temperature	$T_{stg}$		-40 ~ 125		
Isolation voltage	between terminal and copper base (*1)	$V_{isol}$	AC: 1min.	4000	Vrms
Mounting torque of screws to heat sink (*2)		$M_s$	M5 or M6	6.0	N·m
Mounting torque of screws to terminals (*2)		$M_t$	M6	5.0	

(\*1) All terminals should be connected together during the test.

(\*2) Recommendable Value:      Mounting      3.0 ~ 6.0 N·m      (M5 or M6)  
    Terminals      2.5 ~ 5.0 N·m      (M6)

# 2MBI600XHA120-50

IGBT Modules

■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units			
			min.	typ.	max.				
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$	-	-	200	$\mu\text{A}$			
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0\text{V}, V_{GE}=\pm 20\text{V}$	-	-	400	nA			
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20\text{V}$ $I_C = 600\text{mA}$	6.0	6.5	7.0	V			
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15\text{V}$ $I_C = 600\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.70	2.15	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.45	1.90			
	$T_{vj}=125^{\circ}\text{C}$		-	1.85	-				
	$T_{vj}=150^{\circ}\text{C}$		-	1.90	-				
	$T_{vj}=175^{\circ}\text{C}$		-	2.00	-				
Internal Gate resistance	$r_g$	-	-	1.63	-	$\Omega$			
			Capacitance	$V_{CE}=10\text{V}, V_{GE}=0\text{V}, f=1\text{MHz}$	$C_{ies}$	-	63	-	nF
			$C_{oes}$		-	2.1	-		
$C_{res}$	-	0.56	-						
Gate charge	$Q_G$	$V_{CC} = 600\text{V}, I_C = 600\text{A}$ $V_{GE} = -15 \rightarrow +15\text{V}$	-	4000	-	nC			
Forward voltage	$V_F$ (terminal)	$V_{GE} = 0\text{V}$ $I_F = 600\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.90	2.35	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.65	2.10			
	$T_{vj}=125^{\circ}\text{C}$		-	1.70	-				
	$T_{vj}=150^{\circ}\text{C}$		-	1.65	-				
	$T_{vj}=175^{\circ}\text{C}$		-	1.65	-				
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 600\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 0.56 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	400	-	ns		
			$T_{vj}=125^{\circ}\text{C}$	-	410	-			
			$T_{vj}=150^{\circ}\text{C}$	-	415	-			
			$T_{vj}=175^{\circ}\text{C}$	-	420	-			
	$t_r$		$T_{vj}=25^{\circ}\text{C}$	-	95	-			
			$T_{vj}=125^{\circ}\text{C}$	-	100	-			
			$T_{vj}=150^{\circ}\text{C}$	-	100	-			
			$T_{vj}=175^{\circ}\text{C}$	-	105	-			
	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	370	-			
			$T_{vj}=125^{\circ}\text{C}$	-	405	-			
			$T_{vj}=150^{\circ}\text{C}$	-	415	-			
			$T_{vj}=175^{\circ}\text{C}$	-	420	-			
$t_f$	$T_{vj}=25^{\circ}\text{C}$	-	105	-					
	$T_{vj}=125^{\circ}\text{C}$	-	170	-					
	$T_{vj}=150^{\circ}\text{C}$	-	185	-					
	$T_{vj}=175^{\circ}\text{C}$	-	210	-					
Reverse recovery time	$t_{rr}$	$T_{vj}=25^{\circ}\text{C}$	-	295	-				
		$T_{vj}=125^{\circ}\text{C}$	-	285	-				
		$T_{vj}=150^{\circ}\text{C}$	-	590	-				
		$T_{vj}=175^{\circ}\text{C}$	-	635	-				

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

# 2MBI600XHA120-50

IGBT Modules

■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Inverter Switching loss (per pulse)	$E_{on}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 600\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 0.56 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	30.0	-	mJ
			$T_{vj}=125^{\circ}\text{C}$	-	48.7	-	
			$T_{vj}=150^{\circ}\text{C}$	-	53.4	-	
			$T_{vj}=175^{\circ}\text{C}$	-	59.7	-	
	$E_{off}$		$T_{vj}=25^{\circ}\text{C}$	-	38.7	-	
			$T_{vj}=125^{\circ}\text{C}$	-	50.5	-	
			$T_{vj}=150^{\circ}\text{C}$	-	53.5	-	
			$T_{vj}=175^{\circ}\text{C}$	-	55.3	-	
	$E_{rr}$		$T_{vj}=25^{\circ}\text{C}$	-	15.8	-	
			$T_{vj}=125^{\circ}\text{C}$	-	28.2	-	
			$T_{vj}=150^{\circ}\text{C}$	-	31.3	-	
			$T_{vj}=175^{\circ}\text{C}$	-	34.3	-	

NOTICE:

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

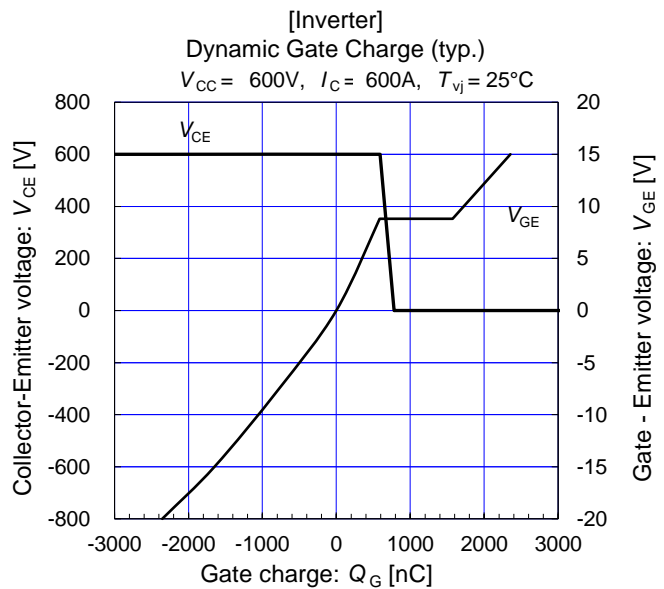
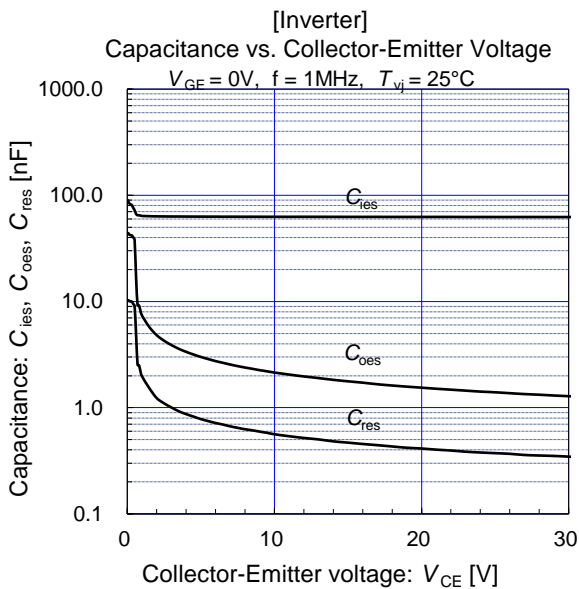
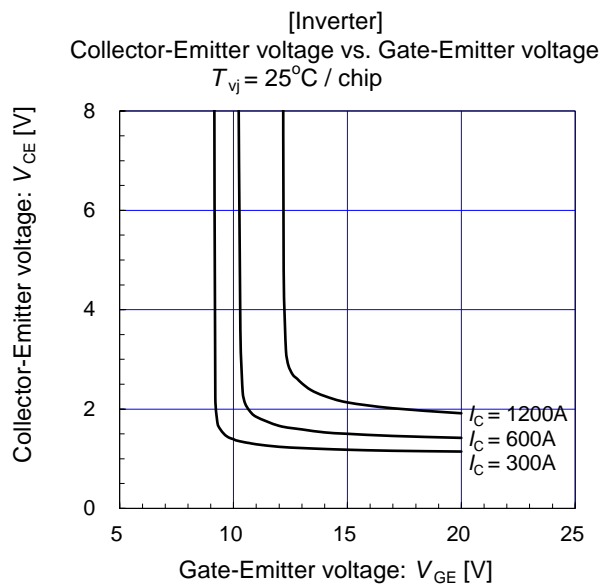
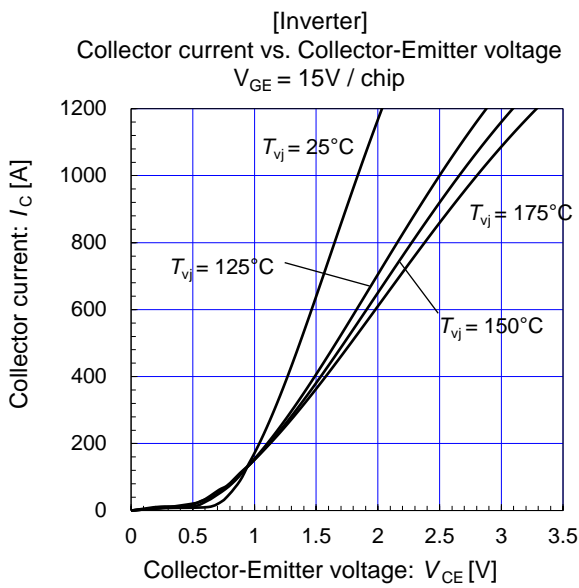
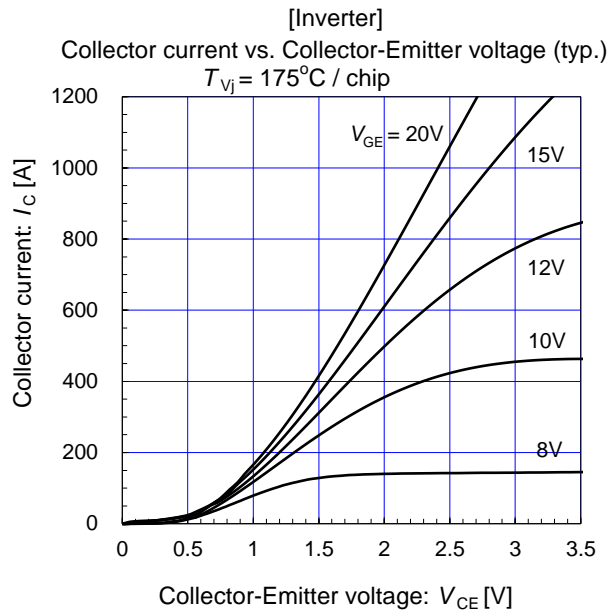
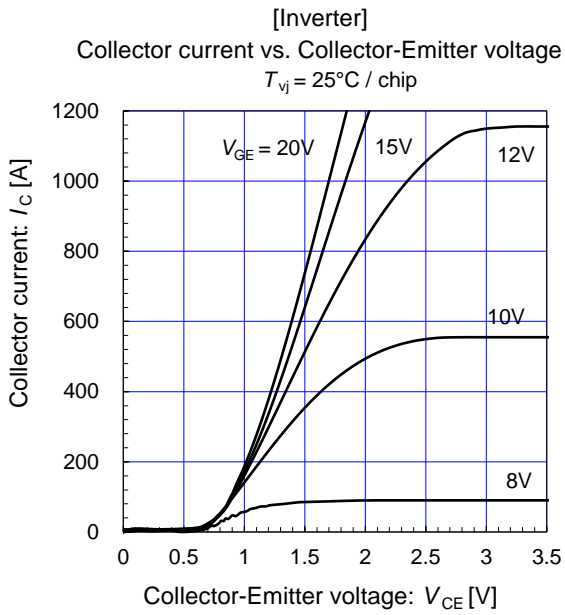
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.064	K/W
		Inverter FWD	-	-	0.090	
Thermal resistance case to heat sink (1IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.0125	-	

(\*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

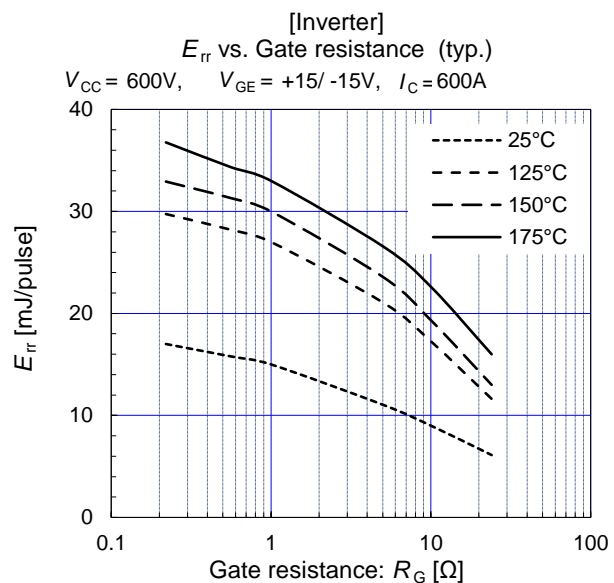
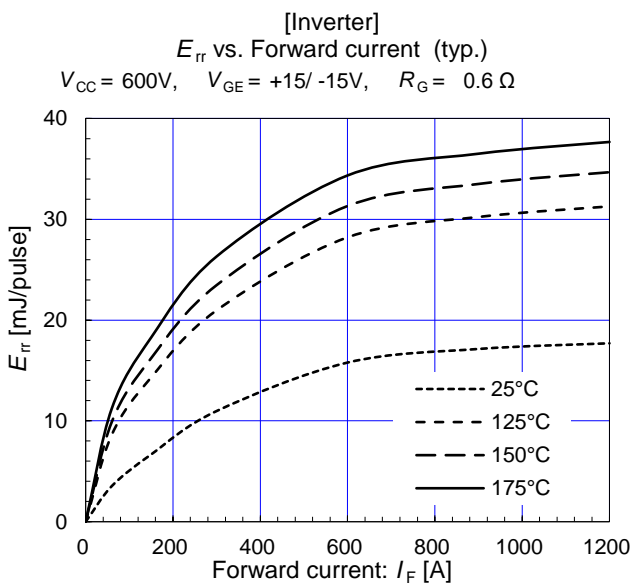
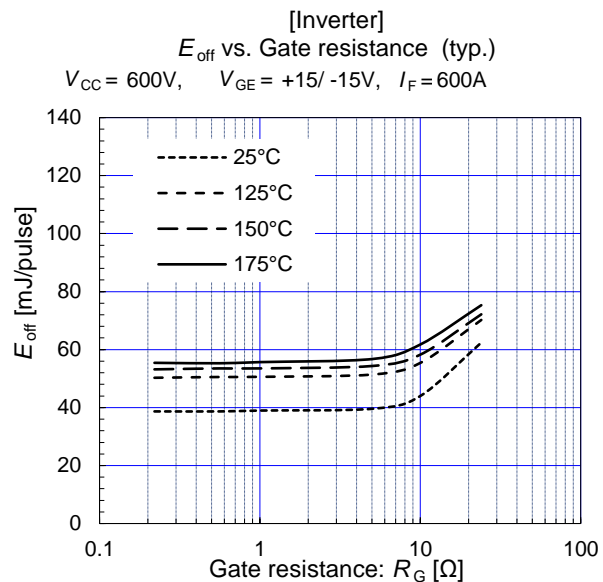
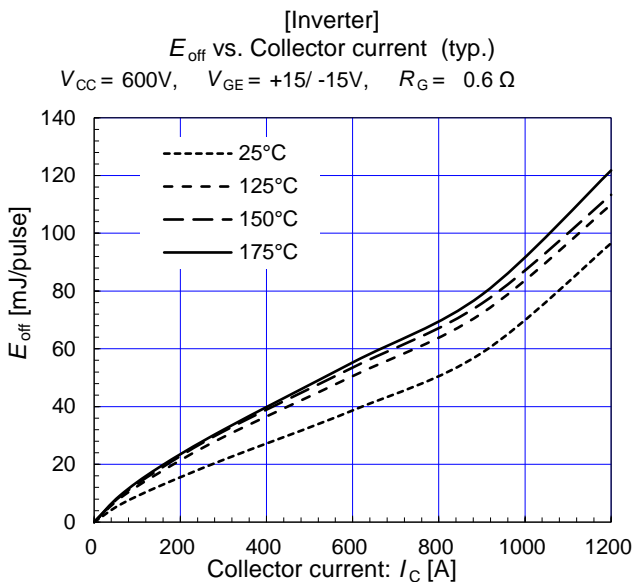
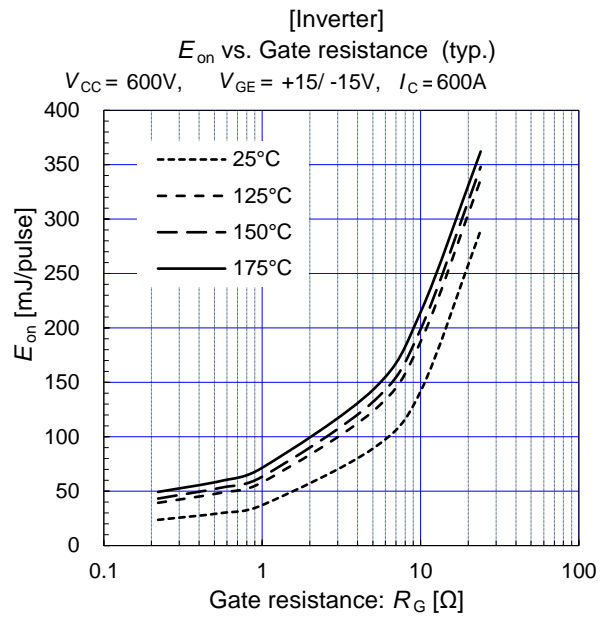
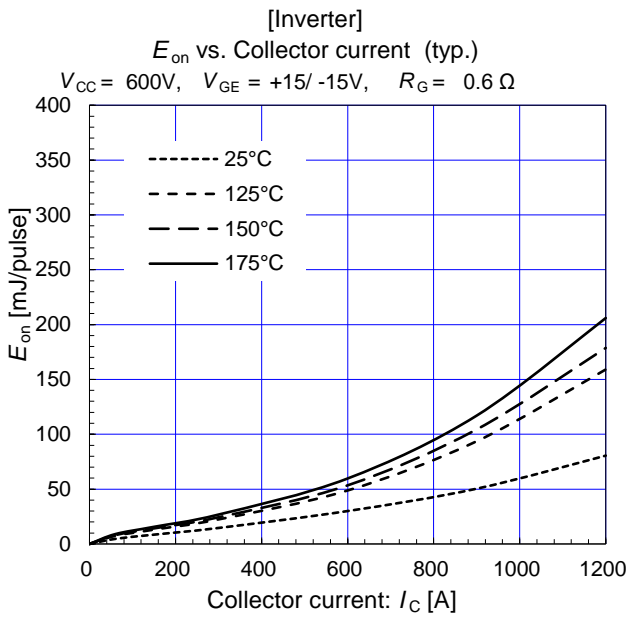
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IGBT Modules



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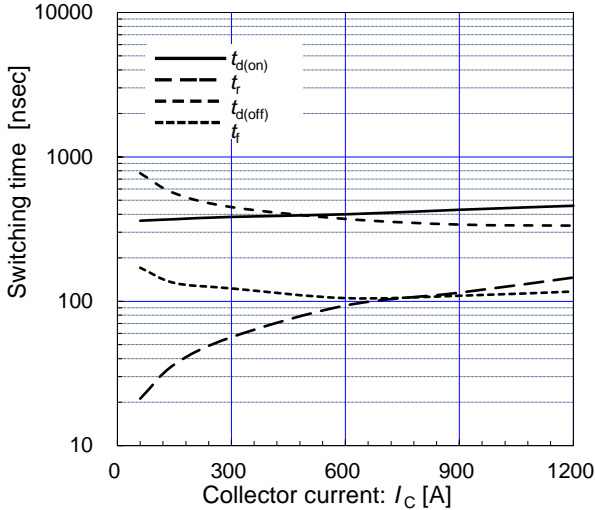


# 2MBI600XHA120-50

[Inverter]

Switching time vs. Collector current (typ.)

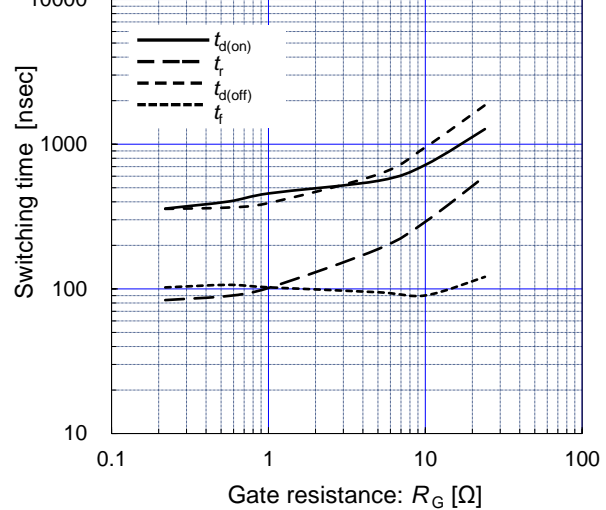
$V_{CC} = 600V, R_G = 0.6\Omega, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

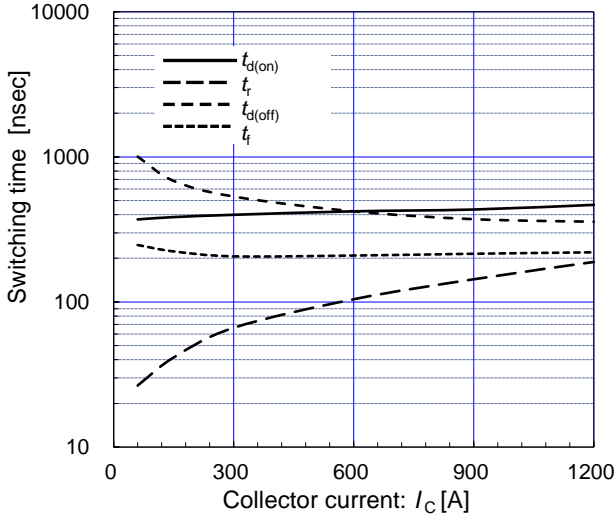
$V_{CC} = 600V, I_C = 600A, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Collector current (typ.)

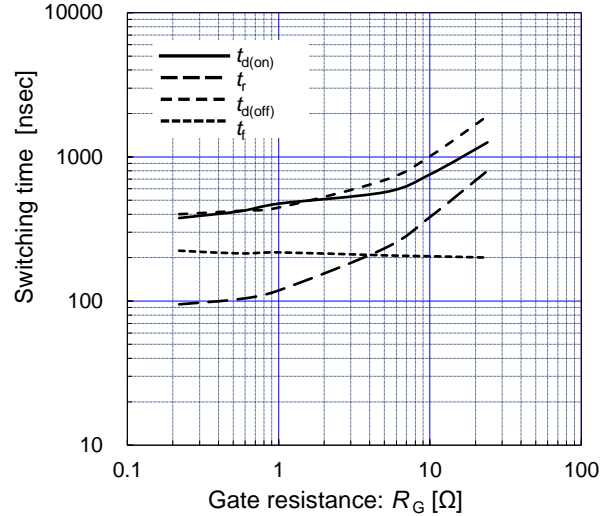
$V_{CC} = 600V, R_G = 0.6\Omega, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

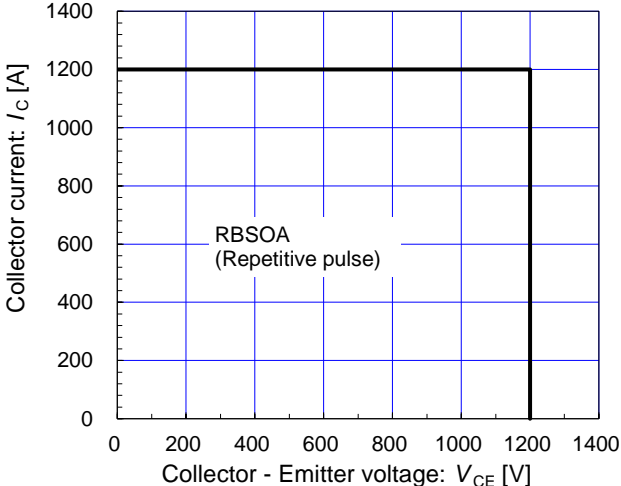
$V_{CC} = 600V, I_C = 600A, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

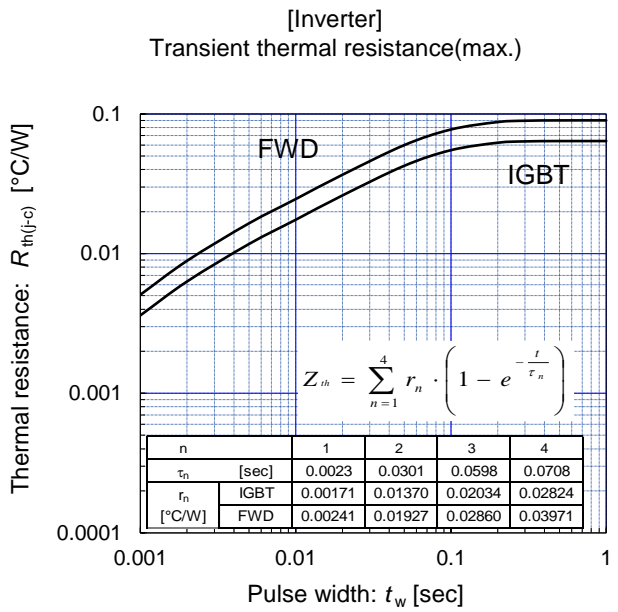
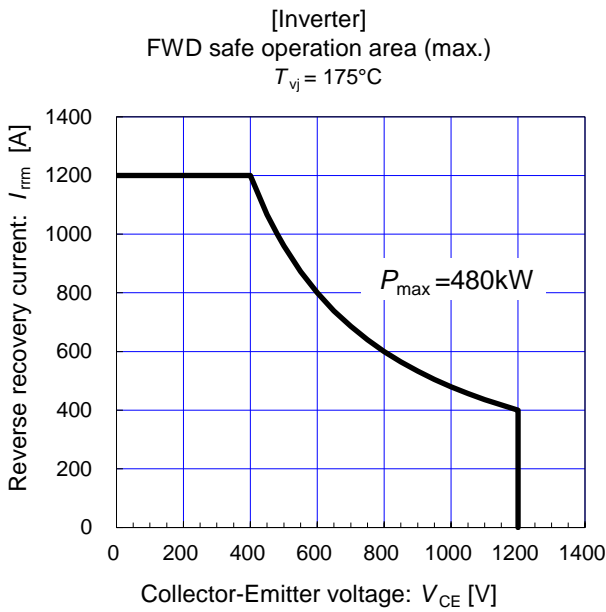
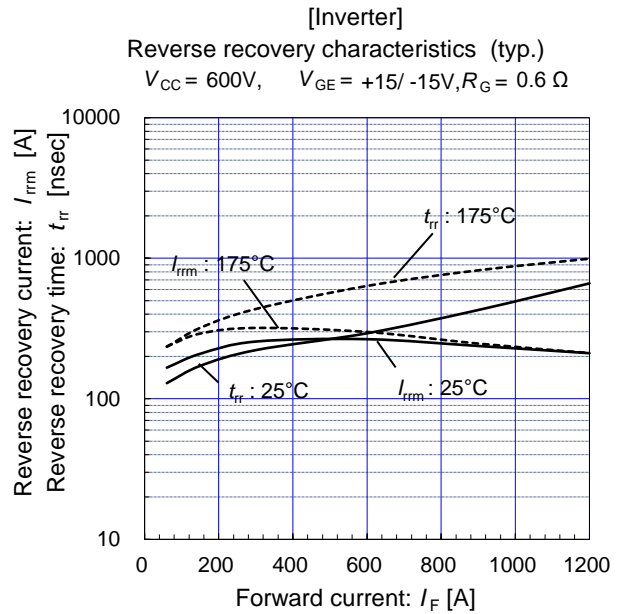
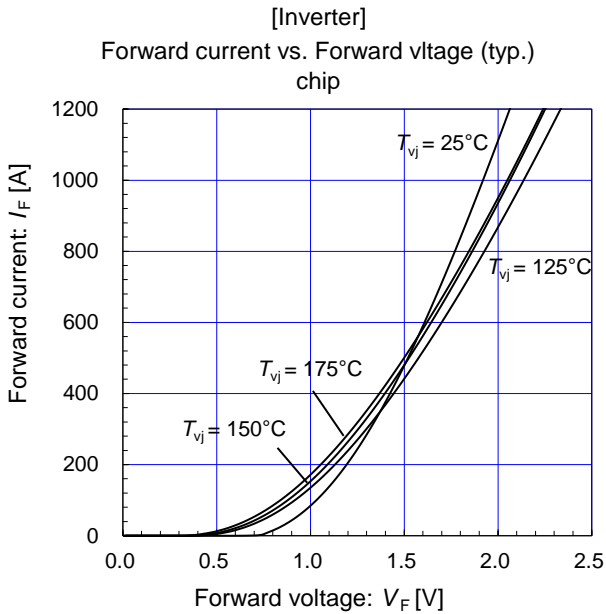
Reverse bias safe operating area (max.)

$V_{GE} = +15/-15V, R_G = 0.56\Omega, T_{vj} = 175^\circ C$



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